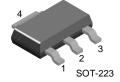


MPSA27/PZTA27

NPN General Purpose Amplifier

- This device is designed for applications requiring extremely high current gain at collector currents to
- Sourced from process 03.
- · See MPSA28 for characteristics.





1. Emitter 2. Base 3. Collector 1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	Collector current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_A=25°C unless otherwise noted

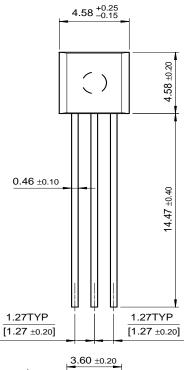
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charact	eristics			•		
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = 100 \mu A, V_{BE} = 0$	60			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_C = 0$	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 100 \mu A, I_C = 0$	10			V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 50V, I_{E} = 0$			100	nA
I _{CES}	Collector Cutoff Current	$V_{CE} = 50V, V_{BE} = 0$			500	nA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 10V, I _C = 0			100	nA
On Characte	eristics					
h _{FE}	DC Current Gain	I _C = 10mA, V _{CE} = 5.0V I _C = 100mA, V _{CE} = 5.0V	10000 10000			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$			1.5	V
V _{BE(on)}	Base-Emitter On Voltage	$I_C = 100 \text{mA}, V_{CE} = 5.0 \text{V}$			2.0	V
Small Signa	I Characteristics					
f _T	Current Gain Bandwidth Product	I _C = 10mA, V _{CE} = 5.0V, f = 100MHz	125			MHz

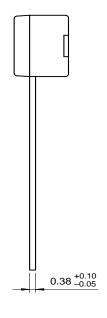
Thermal Characteristics $T_A=25$ °C unless otherwise noted

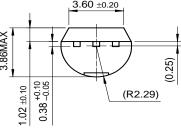
MPSA27	:	Units
IIII OALI	*PZTA27	Units
625	1000	mW
5.0	8.0	mW/°C
83.3		°C/W
200	125	°C/W
	5.0 83.3	5.0 8.0 83.3 200 125

Package Dimensions

TO-92

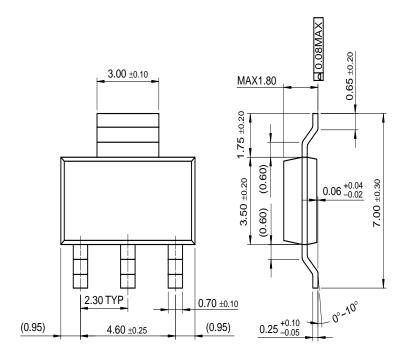


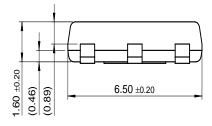




Package Demensions (Continued)

SOT-223





Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS^{TM}	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX^{TM}
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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